



PATENT APPLICATION  
Docket No. 2522-024  
Client No. AW8041US/JY

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: Bong-Hyun Kim, et al. Conf. No. 1246  
Serial No. 10/635,969 Art Unit: 2812  
Filed: August 6, 2003 Examiner: not yet assigned  
For: METHOD OF FORMING A GATE OF A NON-VOLATILE MEMORY  
DEVICE

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Sir:

This Information Disclosure Statement is submitted:

☒ under 37 CFR 1.97 (b); or  
(Within three months of filing national application; or date of entry of International application; or before mailing date of first office action on the merits; whichever occurs last)

☒ Applicant(s) submit herewith Form PTO 1449- Information Disclosure Citation together with copies of patents, publications or other information of which applicant(s) are aware, which applicant(s) believe(s) may be material to the examination of this application and for which there may be a duty to disclose in accordance with 37 CFR 1.56.


It is requested that the information disclosed herein be made of record in this application.

Any deficiency or overpayment should be charged or credited to deposit account number 13-1703. A duplicate copy of this sheet is enclosed.

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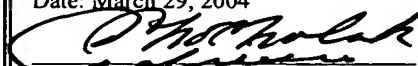
Respectfully submitted,

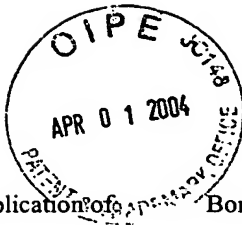
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INFORMATION DISCLOSURE CITATION  
FORM PTO-1449 (Modified)

**FOREIGN PATENT DOCUMENTS**

Exam <u>Init</u>	<u>Ref</u>	Document <u>Number</u>	Publication <u>Date</u>	<u>Country</u>	<u>Name</u>
_____	_____	2000-42639	7/15/2000	Korea	Bok and Cheol

**OTHER DOCUMENTS**

Exam <u>Init</u>	<u>Ref</u>	<u>Author, Title, Date, Pertinent Pages, Etc.)</u>
_____	_____	English language of abstract for Korean Patent Publication No. 2000-42639.

Examiner: \_\_\_\_\_

Date Considered: \_\_\_\_\_

Examiner: \_\_\_\_\_

Date Considered: \_\_\_\_\_